

DESCRIPTION

The A34063A series is a monolithic control circuit containing the primary functions required for DC-DC converters.

These devices consist of internal an temperature-compensated reference, comparator, controlled duty cycle oscillator with an active current limit circuit, driver and high current output switch. This series was specifically designed to be incorporated in step-down and step-up voltage-inverting applications with minimum а number of external components.

The A34063A is available in SOP8 and DIP8 packages.

ORDERING INFORMATION

Package Type	Part Number		
SOP8	M8	A34063AM8R	
		A34063AM8VR	
DIP8	P8	A34063AP8U	
		A34063AP8VU	
	V: Halogen free Package R: Tape & Reel		
Note			
	U: Tube		

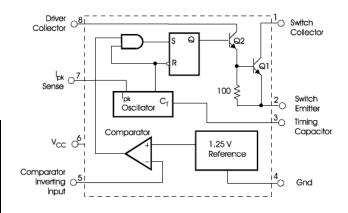
AiT provides all RoHS products

Suffix "V" means Halogen free Package

FEATURES

- Operation from 3.0V to 40V input
- Low standby current
- Current limiting
- Output switch current up to 1.5 A
- Adjustable output voltage
- Operation at frequencies up to 100kHz
- Precision Reference (2%)
- Available in SOP8 and DIP8 Packages

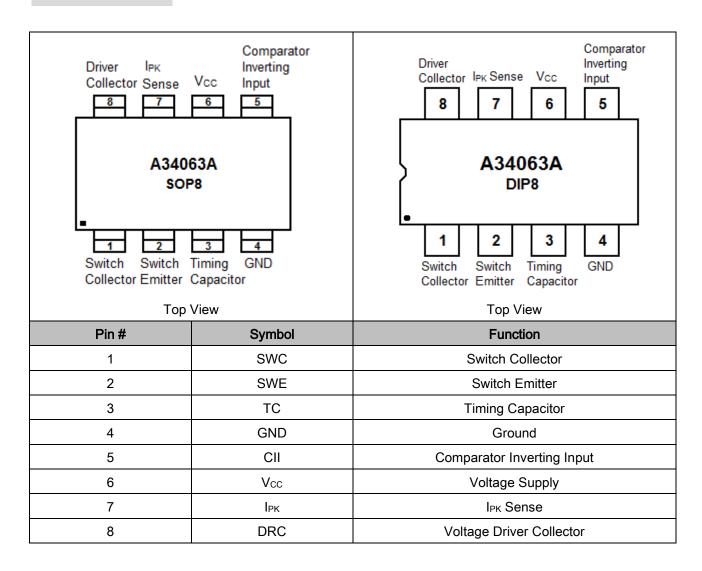
TYPICAL APPLICATION



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PIN DESCRIPTION



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ABSOLUTE MAXIMUM RATINGS

Vcc, Power Supply Voltage	40V _{DC}
V _{IR} , Comparator Input Voltage Range	-0.3 to +40V _{DC}
V _{C(Switch)} , Switch Collector Voltage	40V _{DC}
V _{E(Switch)} , Switch Emitter Voltage (V _{Pin1} =40V)	40V _{DC}
V _{CE(Switch)} , Switch Collector-to-Emitter Voltage	$40V_{DC}$
V _{C(Driver)} , Driver Collector Voltage	40V _{DC}
I _{C(Driver)} , Driver Collector Current ^{NOTE1}	100mA
I _{sw} , Switch Current	1.5A
T _J , Operating Junction Temperature	+150°C
T _A , Operating Ambient Temperature Range	-40°C ~ +85°C
T _{STG} , Storage Temperature Range	-65°C ~ + 150°C
ESD	2500V

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: Maximum package power dissipation limits must be observed.

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ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
OSCILLATOR						
Frequency	f _{osc}	V _{Pin5} =0V, C _T =1.0nF, T _A =25°C	24	33	42	KHz
Charge current	I _{chg}	V _{CC} =5.0V to 40V, T _A =25°C	24	35	42	μA
Discharge current	I _{dischg}	V _{CC} =5.0V to 40V, T _A =25°C	140	220	260	μA
Discharge-to-charge current ratio	Idischg/Ichg	Pin7 to V _{CC} , T _A =25°C	5.2	6.5	7.5	
Current limit sense voltage	V _{lpk(sense)}	I _{chg} =I _{dischg} , T _A =25°C	250	300	350	mV
OUTPUT SWITCH NOTE 2	•			•		
Saturation voltage, Darlington connection	V _{CE(sat)}	I _{Sw} =1.0A, Pins1, 8 connected		1.0	1.3	V
Saturation voltage, Darlington connection	V _{CE(sat)}	I_{Sw} =1.0A, R_{Pin8} =82Ω to V_{CC} , Forced $β$ =20		0.45	0.7	V
DC current gain	h _{FE}	I _{Sw} =1.0A, V _{CE} =5.0, T _A =25°C	50	75		
Collector off-state current	I _{C(off)}	V _{CE} =40V		40	100	μΑ
COMPARATOR						
Threshold voltage	V _{th}		1.225 1.21	1.25	1.275 1.29	V
Threshold voltage line regulation	Regline			1.4	5.0	mV
Input bias current	I _{IB}			-20	-400	nΑ
TOTAL DEVICE						
Supply current	Icc	V _{CC} =5.0V to 40V, C _T =1.0nF, Pin7=V _{CC} , V _{Pin5} >V _{th} , Pin2 =GND, remaining pins - open			4.0	mA

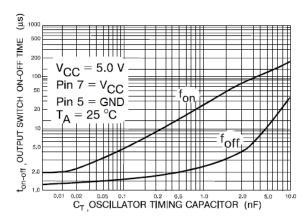
NOTE2: Low duty cycle pulse techniques are used during the test to maintain junction temperature as close to ambient temperature as possible.

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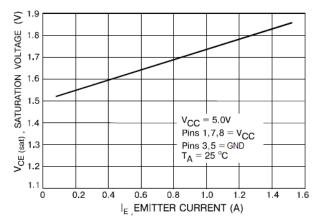


TYPICAL PERFORMANCE CHARACTERISTICS

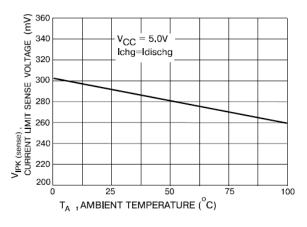
Output Switch on-off time versus
 Oscillator timing capacitor



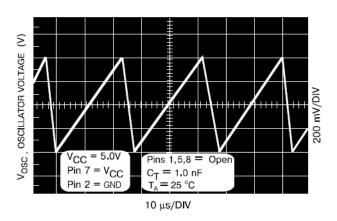
 Emitter follower configuration output saturation voltage versus Emitter current



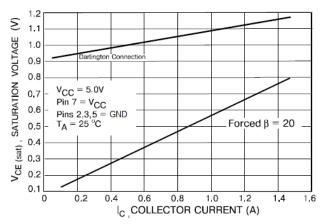
5. Current limit sense voltage versus Temperature



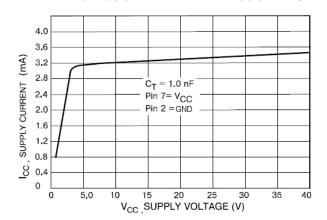
2. Timing capacitor waveform



4. Common emitter configuration output saturation voltage versus Collector current



6. Standby supply current versus Supply voltage

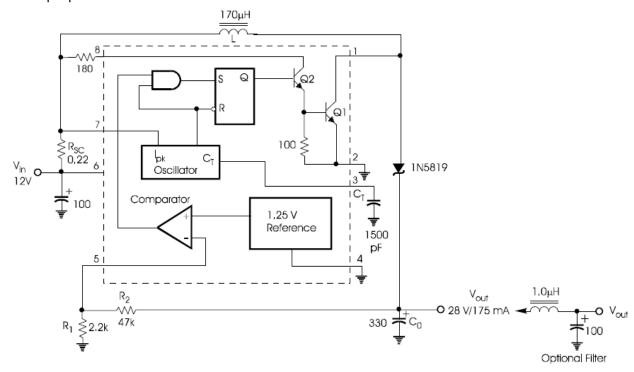


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DETAILED INFORMATION

Application Information

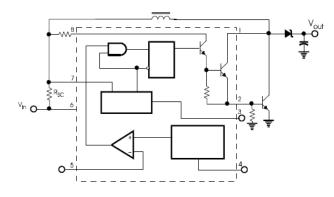
1. Step-up converter

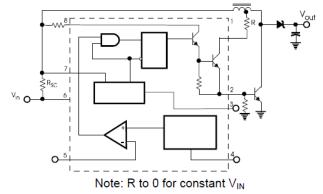


2. External current boost connections for I_{C Peak} greater than 1.5A

External NPN switch□

External NPN saturated switch

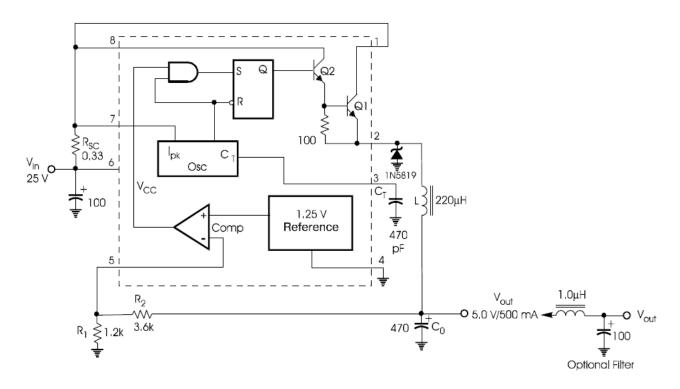




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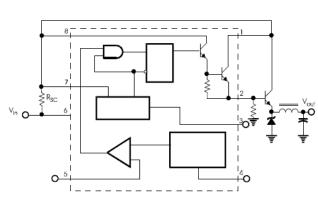


3. Step-down Converter

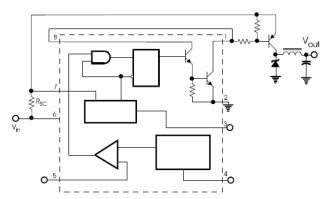


4. External current boost connections for Ic Peak greater than 1.5A

External NPN switch□



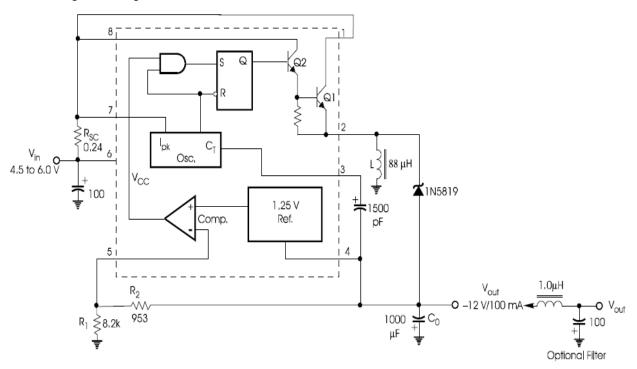
External PNP saturated switch



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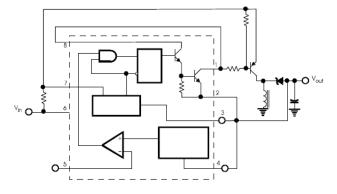
5. Voltage inverting converter



6. External current boost connections for Ic Peak greater than 1.5A

External NPN switch

External PNP saturated switch



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Design Formula

Calculation	Step-up	Step-down	Voltage-inverting
t _{on}	$\frac{V_{out} + V_F - V_{in(\min)}}{V_{in(\min)} - V_{sat}}$	$\frac{V_{out} + V_F}{V_{in(min)} - V_{sat} - V_{out}}$	$\frac{\left V_{out}\right + V_F}{V_{in} + V_{sat}}$
(ton + toff) max	$\frac{1}{f_{min}}$	$\frac{1}{f_{min}}$	$\frac{1}{f_{min}}$
Ст	4.0 x 10 ⁻⁵ t _{on}	4.0 x 10 ⁻⁵ t _{on}	4.0 x 10 ⁻⁵ t _{on}
I _{pk(switch)}	$2I_{out(max)} \left(\frac{t_{on}}{t_{off}} + 1 \right)$	$2I_{out(\max)}$	$2I_{out(max)} \left(\frac{t_{on}}{t_{off}} + 1 \right)$
R _{sc}	0.3/I _{pk(Switch)}	$0.3/I_{pk(Switch)}$	$0.3/I_{pk(Switch)}$
L _(min)	$\left(\frac{V_{in(\min)} - V_{sat}}{I_{pk(switch)}}\right) \times t_{on(\max)}$	$\left(\frac{\boldsymbol{V}_{in(\min)} - \boldsymbol{V}_{sat} - \boldsymbol{V}_{out}}{\boldsymbol{I}_{pk(switch)}}\right) \times \boldsymbol{t}_{on(\max)}$	$\left(\frac{\boldsymbol{V}_{in(\min)} - \boldsymbol{V}_{sat}}{\boldsymbol{I}_{pk(switch)}}\right) \times \boldsymbol{t}_{on(\max)}$
Co	$9 \frac{I_{out}t_{on}}{V_{ripple(pp)}}$	$\frac{I_{\textit{pk(switch)}}(t_{\textit{on}} + t_{\textit{off}})}{8V_{\textit{ripple(pp)}}}$	$9 \frac{I_{out}t_{on}}{V_{ripple(pp)}}$

Terms and Definitions

 V_{sat} – Saturation voltage of the output switch.

V_f – Forward voltage drop of the output rectifier.

The following power supply characteristics must be chosen:

V_{IN} – Nominal input voltage.

Vout - Desired output voltage,

$$|V_{out}| = 1.25 \left(1 + \frac{R_2}{R_1}\right)$$

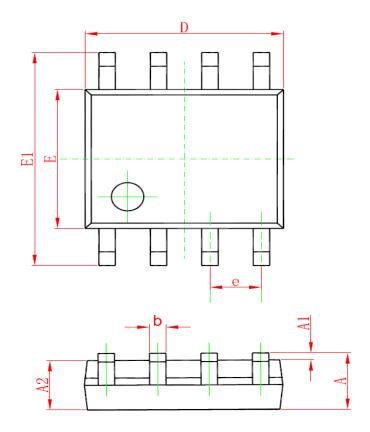
 f_{min} – Minimum desired output switching frequency at the selected values of V_{IN} and I_{OUT} .

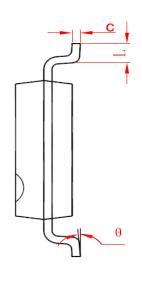
 $V_{ripple(p-p)}$ – Desired peak-to-peak output ripple voltage. In practice, the calculated capacitor value will need to be increased due to its equivalent series resistance and board layout. The ripple voltage should be kept to a low value since it will directly affect the line and load regulation.

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PACKAGE INFORMATION

Dimension in SOP8 (Unit: mm)

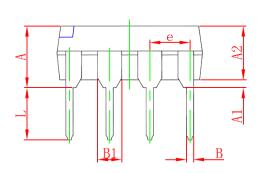


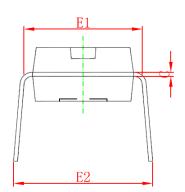


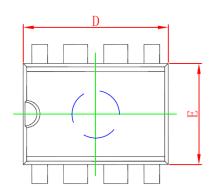
Symbol	Min	Max	
Α	1.350	1.750	
A1	0.100	0.250	
A2	1.350	1.550	
b	0.330	0.510	
С	0.170	0.250	
D	4.700	5.100	
Е	3.800	4.000	
E1	5.800	6.200	
е	1.270(BSC)		
L	0.400	1.270	
θ	0°	8°	

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Dimension in DIP8 (Unit: mm)







Symbol	Min	Max	
Α	3.710	4.310	
A1	0.510		
A2	3.200	3.600	
В	0.380	0.570	
B1	1.524(BSC)		
С	0.204	0.360	
D	9.000	9.400	
E	6.200	6.600	
E1	7.320	7.920	
е	2.540(BSC)		
L	3.000	3.600	
E2	8.400	9.000	

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